

THR60U12DK



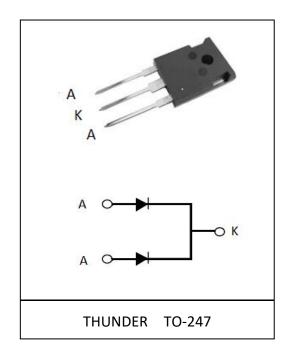
Thunder High Power Products

FRED Ultrafast Soft Recovery Diode, 60A

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity
- Epitaxial chip construction

Product Summary		
Vr	1200 V	
IF(AV)	2*30A	
trr	32 ns	



Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		1200	V
Continuous forward current	lf(AV)	Tc =110°C	60	
Single pulse forward current	IFSM	Tc =25°C	600	А
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	80	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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Electrical characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage	VBR,	Ir=100μA	1200			
Blocking voltage	V _R					
Forward voltage (Per Diode)	VF	I _F =30A		2.10	2.70	V
	VI	I_F =30A, T_j =125 $^{\circ}$ C		1.85	2.20	
Reverse leakage current(Per Diode)		VR= VRRM			20	
	lR	Tj=150°C, V _R =1200V			200	μ Α
Reverse recovery time(Per Diode)	trr	I _F =0.5A, I _R =1A, I _{RR} =0.25A		50	70	ns
		$I_F=1A, V_R=30V, di/dt = 200A/us$		32	50	

Thermal characteristics

Paramter	Symbol	Тур	Units
Junction-to-Case	$R_{ heta JC}$	0.75	°C/W

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Electrical performance (Typical)

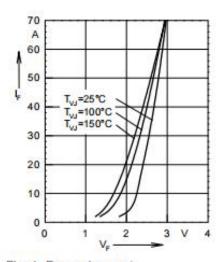


Fig. 1 Forward current versus voltage drop.

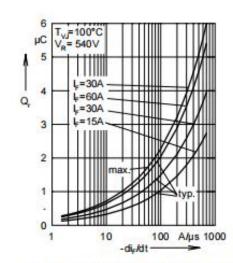


Fig. 2 Recovery charge versus -di_r/dt.

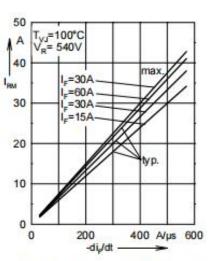


Fig. 3 Peak reverse current versus -di_/dt.

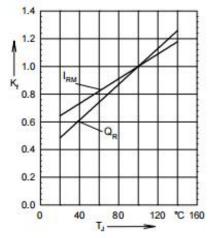


Fig. 4 Dynamic parameters versus junction temperature.

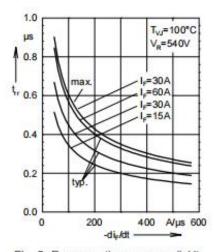


Fig. 5 Recovery time versus -di_/dt.

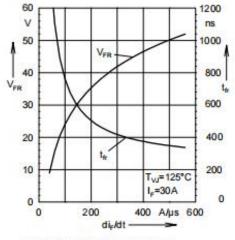


Fig. 6 Peak forward voltage versus di./dt.

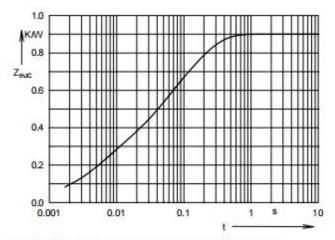


Fig. 7 Transient thermal impedance junction to case.

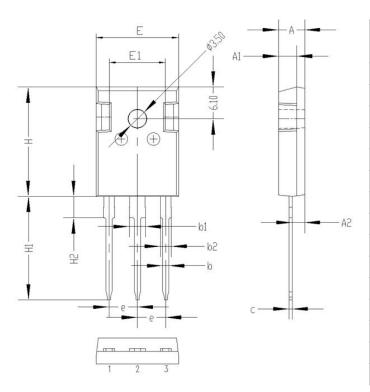
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Package Information

TO-247 PACKAGE



Symbol	Dimensions(millimeters	
Symbol	Min.	Max.
Α	4.80	5.20
A1	3.30	3.70
A2	2.10	2.50
b	1.00	1.40
b1	2.90	3.30
b2	1.90	2.30
С	0.40	0.80
е	5.25	5.65
Е	15.6	16.0
E1	10.6	11.00
Н	20.8	21.2
H1	19.4	20.4
H2	3.90	4.30
G	5.90	6.30
ΦР	3.30	3.70

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